

Lms36PD-03-TEM-R

| Device parameters | Symbol | Value | Units |
|---|-------------------|--------|-------|
| Sensitive area size | d | 0.3 | mm |
| Reverse voltage | V_r | 0.1 | V |
| Operating/ storage temperature | T_{opr}/T_{stg} | +5+90* | °C |
| Soldering temperature (can be applied for not more than 5 secs) | T _{sol} | +180 | °C |



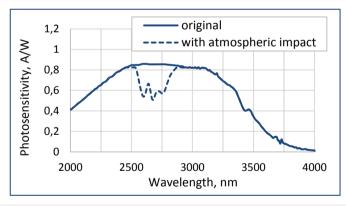
^{*}Photodiode design for different storage/operating temperature range can be considered under request.

All parameters refer to photodiode operation at ambient temperature 25°C unless otherwise stated.

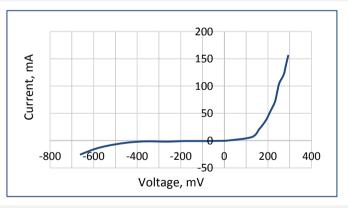
| Photodiode parameters | Conditions | Symbol | Value | Units |
|--|-----------------------|-----------------|--|--|
| Cut-off wavelength (at 10% level) ¹ | - | λ_{cut} | 3.7 - 3.8 | μm |
| Max. sensitivity range (at 80% level) ¹ | - | λ_{p} | 2.45 - 3.30 | μm |
| Dark current (typical/ maximal) ² | $V_r = 0.1 V$ | I _d | typ 150 / max 600 | μΑ |
| Shunt resistance (minimal/ typical) ² | $V_r = 10 \text{ mV}$ | R_{sh} | min 0.2 / typ 0.6 | kΩ |
| Capacitance (typical/ maximal) ¹ | $V_r = 10 \text{ mV}$ | С | typ 200 / max 300 | pF |
| Photosensitivity (minimal/ typical) ² | λ = 3.3 μm | S | min 0.7 / typ 0.8 | A/W |
| Noise equivalent power (typical/ maximal) ² | λ = 3.3 μm | NEP | typ 6.5*10 ⁻¹² / max 13*10 ⁻¹² | W/Hz ^{1/2} |
| Detectivity (minimal/ typical) ² | $\lambda = 3.3 \mu m$ | D* | min 2.4*10° / typ 4.7*10° | cm [·] Hz ^{1/2} ·W ⁻¹ |

¹ Parameter tested for representative sampling.

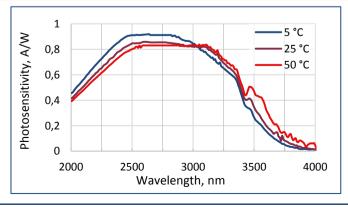
Typical spectral response



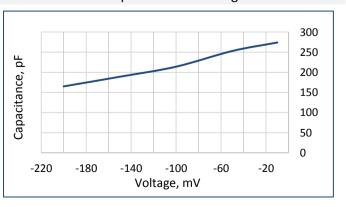
Typical current-voltage characteristic



Temperature shift of spectral response



Capacitance vs. voltage



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² Parameter tested for each device.

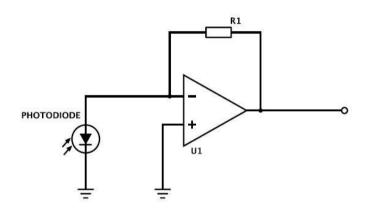
| Packages* | Model |
|--|------------------|
| TO-18 with a cap without a glass window | Lms36PD-03 |
| TO-18 with a parabolic reflector without a glass window | Lms36PD-03-R |
| TO-18 with a parabolic reflector with a glass window | Lms36PD-03-RW |
| TO-5 with a built-in thermocooler and thermoresistor, covered by a cap with a glass window | Lms36PD-03-TEM |
| TO-5 with a built-in thermocooler and thermoresistor, covered by a parabolic reflector with a glass window | Lms36PD-03-TEM-R |
| PD with a built-in preamplifier; TO-18 with a parabolic reflector without a window in an aluminum tube | Lms36PD-03-R-PA |
| PD with a built-in preamplifier; TO-18 with a parabolic reflector with a window in an aluminum tube | Lms36PD-03-RW-PA |

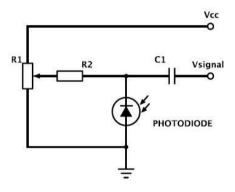
^{*}Standard photodiode packaging is non-hermetical, so that condensation during device operation and storage must be prevented.

Recommended modes of PD operation

PD used as a current source (photovoltaic mode)

PD used in a photoconductive mode (under reverse bias)





We recommend using **photovoltaic mode**, when PD is used under no reverse bias. Use photoconductive mode (mode with reverse bias) with caution.

IMPORTANT CAUTIONS:

- please check your connection circuit before turning on the PD;
- please mind the PD polarity: PD anode is marked with a RED dot;
- please do not connect the PD to the multimeter.

Related products:

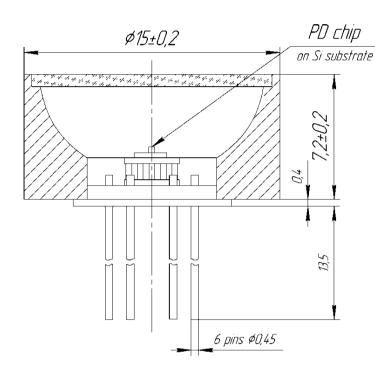
- Light emitting diodes (LEDs) sources of IR radiation;
- PAb preamplifier amplifies photocurrent generated by a PD and converts it into a voltage signal;
- **SDM synchronous detector** enables synchronous operation of a PD coupled with a preamplifier and an LED coupled with a driver; performs convertion of an output PD preamplifier signal into DC voltage signal.

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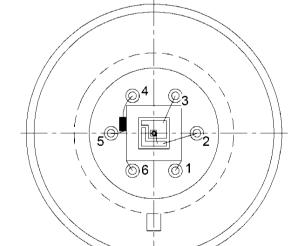
Technical Drawing

Lms36PD-03-TEM-R

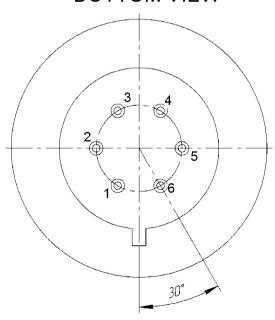


- 1 TEC +
- 2 PD anode 3 PD cathode
- 4 thermistor
- 5 thermistor
- 6 TEC -

TOP VIEW



BOTTOM VIEW



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